# BAW56/BAV70/BAV99



### BAW56/BAV70/BAV99

SWITCHING DIODE

#### FEATURES

- Fast Switching Speed
- For General Purpose Switching Applications
- High Conductance









BAW56 Marking: A1

BAV70 Marking: A4

BAV99 Marking: A7

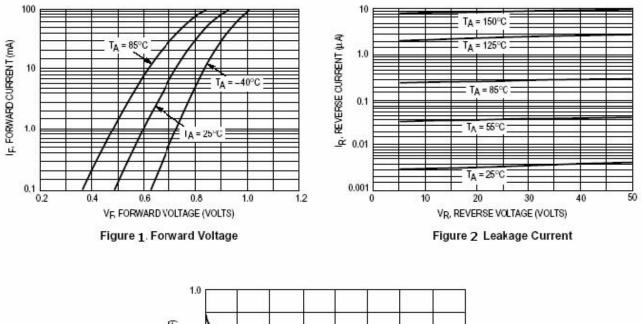
#### Maximum Ratings @TA=25℃

Parameter	Symbol	Limits	Unit
Reverse voltage	VR	70	V
Forward Current	lF	200	mA
Peak Forward Surge Current	FM(surge)	500	mA
Power Dissipation	PD	225	mW
Thermal Resistance Junction to Ambient Air	Reja	556	°C/W
Junction temperature	TJ	150	°C
Storage temperature range	Tstg	-55-150	°C

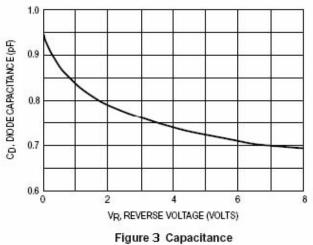
#### Electrical Characteristics @TA=25°C

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Reverse Breakdown Voltage	V r	70			V	Ι <sub>R</sub> =100μΑ
Forward voltage	VF1			0.715	V	I⊧=1mA
	VF2			0.855	V	I⊧=10mA
	VF3			1	V	I⊧=50mA
	VF4			1.25	V	I⊧=150mA
Reverse current	lr			2.5	μA	V <sub>R</sub> =70V
Capacitance between terminals	Ст			1.5	pF	V <sub>R</sub> =0,f=1MHz
Reverse recovery time	trr			6	ns	$I_F = I_R = 10$ mA, Irr= 0.1 x I <sub>R</sub> , R <sub>L</sub> = 100 $\Omega$





## **Typical Characteristics**



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